## TOSHIBA

TOSHIBA PHOTOCOUPLER GaAs IRED & PHOTO-TRIAC

## TLP3031(S), TLP3032(S), TLP3033(S)

OFFICE MACHINE

HOUSEHOLD USE EQUIPMENT

TRIAC DRIVER

**SOLID STATE RELAY** 

The TOSHIBA TLP3031 (S), TLP3032 (S), TLP3033 (S) consist of a zero voltage crossing turn-on photo-triac optically coupled to a gallium arsenide infrared emitting diode in a six lead plastic DIP. All parameters are tested to the specification of TLP3031, TLP3032, TLP3033.

Peak Off-State Voltage: 250 V (Min.)

Trigger LED Current : 15 mA (Max.) (TLP3031)

> 10 mA (Max.) (TLP3032) 5 mA (Max.) (TLP3033)

On-State Current : 100 mA (Max.)

**UL** Recognized : UL1577, File No. E67349

Isolation Voltage :  $5000 \, \mathrm{V_{rms}}$  (Min.)

SEMKO Approved : SS EN60065

SS EN60950

SS EN60335

Option (D4) Type

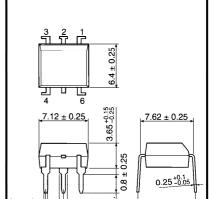
VDE Approved : DIN VDE0884/06.92

Certificate No. 68329

Maximum Operating Insulation Voltage: 890 Vpk Highest Permissible Over Voltage : 8000 VPK

When a VDE0884 approved type is needed, please

designate the "Option (D4)"



Unit in mm

7.85~8.80

		11-7A9
JEDEC	_	
EIAJ	_	

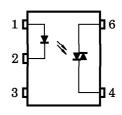
Weight: 0.39 g

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 $2.54 \pm 0.25$ 

PIN CONFIGURATION (Top view)

11-7A9



1: ANODE

2: CATHODE

3 : N.C.

4: TERMINAL 1 6: TERMINAL 2

TOSHIBA is continually working to improve the quality and the reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to observe standards of safety, and to avoid situations in which a malfunction or failure of a TOSHIBA product could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent products specifications. Also, please keep in mind the precautions and conditions set forth in the TOSHIBA Semiconductor Reliability Handbook.

Gallium arsenide (GaAs) is a substance used in the products described in this document. GaAs dust and fumes are toxic. Do not break, cut or pulverize the product, or use chemicals to dissolve them. When disposing of the products, follow the appropriate regulations. Do not dispose of the products with other industrial waste or with domestic

garbage.

The products described in this document are subject to the foreign exchange and foreign trade laws.

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The information contained herein is subject to change without notice.

	7.62 mm pich standard type	10.16 mm pich (LF2) type
Creepage Distance	7.0 mm (Min.)	8.0 mm (Min.)
Clearance	7.0 mm (Min.)	8.0 mm (Min.)
Insulation Thickness	0.5 mm (Min.)	0.5 mm (Min.)